# PDTC144E series

NPN resistor-equipped transistors; R1 = 47 k $\Omega$ , R2 = 47 k $\Omega$ 

Rev. 9 — 15 November 2011

**Product data sheet** 

## 1. Product profile

### 1.1 General description

NPN Resistor-Equipped Transistor (RET) family in Surface-Mounted Device (SMD) plastic packages.

Table 1. Product overview

Type number	Package	cage		PNP	Package
	NXP	JEITA	JEDEC	complement	configuration
PDTC144EE	SOT416	SC-75	-	PDTA144EE	ultra small
PDTC144EM	SOT883	SC-101	-	PDTA144EM	leadless ultra small
PDTC144ET	SOT23	-	TO-236AB	PDTA144ET	small
PDTC144EU	SOT323	SC-70	-	PDTA144EU	very small

### 1.2 Features and benefits

- 100 mA output current capability
- Built-in bias resistors
- Simplifies circuit design
- Reduces component count
- Reduces pick and place costs
- AEC-Q101 qualified

### 1.3 Applications

- Digital applications in automotive and industrial segments
- Control of IC inputs

- Cost-saving alternative for BC847/857 series in digital applications
- Switching loads

#### 1.4 Quick reference data

Table 2. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{CEO}$	collector-emitter voltage	open base	-	-	50	V
Io	output current		-	-	100	mA
R1	bias resistor 1 (input)		33	47	61	$k\Omega$
R2/R1	bias resistor ratio		0.8	1	1.2	



## 2. Pinning information

Table 3. **Pinning** Simplified outline **Graphic symbol** Pin Description SOT23; SOT323; SOT416 1 input (base) 3 GND (emitter) 2 3 output (collector) 006aaa144 sym007 **SOT883** 1 input (base) 2 GND (emitter) output (collector) Transparent

## 3. Ordering information

Table 4. Ordering information

Type number	Package						
	Name	Description	Version				
PDTC144EE	SC-75	plastic surface-mounted package; 3 leads	SOT416				
PDTC144EM	SC-101	leadless ultra small plastic package; 3 solder lands; body 1.0 $\times$ 0.6 $\times$ 0.5 mm	SOT883				
PDTC144ET	-	plastic surface-mounted package; 3 leads	SOT23				
PDTC144EU	SC-70	plastic surface-mounted package; 3 leads	SOT323				

## 4. Marking

Table 5. Marking codes

08
E7
*08
*08
E *(

[1] \* = placeholder for manufacturing site code

## 5. Limiting values

Table 6. Limiting values

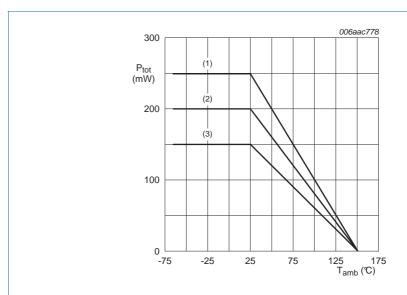
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CBO}$	collector-base voltage	open emitter	-	50	V
$V_{CEO}$	collector-emitter voltage	open base	-	50	V
$V_{EBO}$	emitter-base voltage	open collector	-	10	V
$V_{I}$	input voltage				
	positive		-	+40	V
	negative		-	-10	V
Io	output current		-	100	mA
I <sub>CM</sub>	peak collector current	$single \ pulse; \\ t_p \leq 1 \ ms$	-	100	mA
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25  ^{\circ}C$			
	PDTC144EE (SOT416)		[1][2]	150	mW
	PDTC144EM (SOT883)		[2][3]	250	mW
	PDTC144ET (SOT23)		[1] -	250	mW
	PDTC144EU (SOT323)		[1] -	200	mW
T <sub>j</sub>	junction temperature		-	150	°C
T <sub>amb</sub>	ambient temperature		-65	+150	°C
T <sub>stg</sub>	storage temperature		-65	+150	°C

<sup>[1]</sup> Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

<sup>[2]</sup> Reflow soldering is the only recommended soldering method.

<sup>[3]</sup> Device mounted on an FR4 PCB with 70  $\mu m$  copper strip line, standard footprint.



- (1) SOT23; FR4 PCB, standard footprint SOT883; FR4 PCB with 70  $\mu m$  copper strip line, standard footprint
- (2) SOT323; FR4 PCB, standard footprint
- (3) SOT416; FR4 PCB, standard footprint

Fig 1. Power derating curves

### 6. Thermal characteristics

Table 7. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air				
	PDTC144EE (SOT416)		[1][2]	-	830	K/W
	PDTC144EM (SOT883)		[2][3]	-	500	K/W
	PDTC144ET (SOT23)		[1] -	-	500	K/W
	PDTC144EU (SOT323)		<u>[1]</u> _	-	625	K/W

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [2] Reflow soldering is the only recommended soldering method.
- [3] Device mounted on an FR4 PCB with 70  $\mu m$  copper strip line, standard footprint.

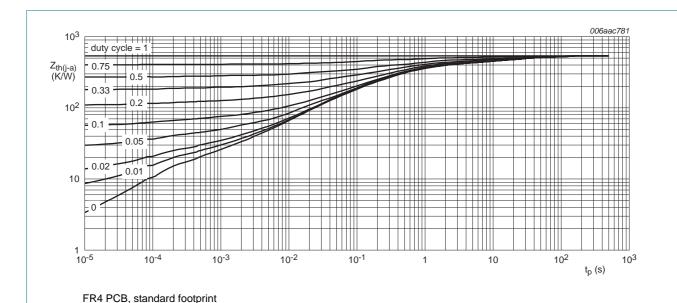


Fig 2. Transient thermal impedance from junction to ambient as a function of pulse duration for PDTC144EE (SOT416); typical values

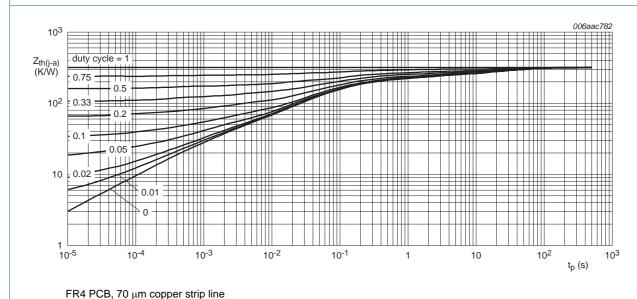
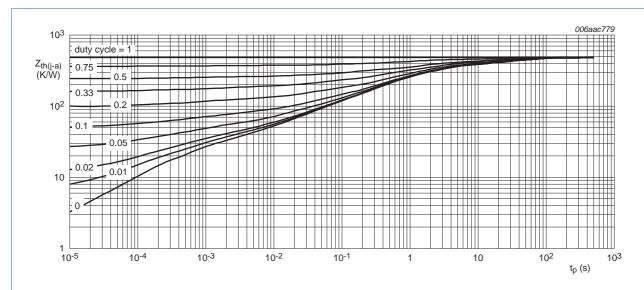
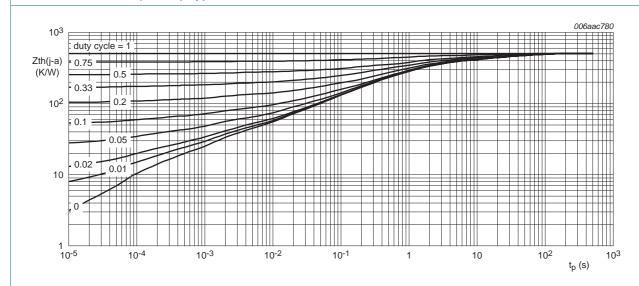


Fig 3. Transient thermal impedance from junction to ambient as a function of pulse duration for PDTC144EM (SOT883); typical values



FR4 PCB, standard footprint

Fig 4. Transient thermal impedance from junction to ambient as a function of pulse duration for PDTC144ET (SOT23); typical values



FR4 PCB, standard footprint

Fig 5. Transient thermal impedance from junction to ambient as a function of pulse duration for PDTC144EU (SOT323); typical values

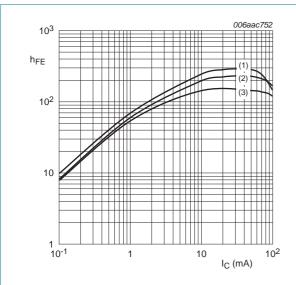
## 7. Characteristics

Table 8. Characteristics

 $T_{amb} = 25$  °C unless otherwise specified.

Symbol	Parameter	Conditions	N	lin	Тур	Max	Unit
I <sub>CBO</sub>	collector-base cut-off current	$V_{CB} = 50 \text{ V}; I_E = 0 \text{ A}$	-		-	100	nA
I <sub>CEO</sub>	collector-emitter cut-off current	$V_{CE} = 30 \text{ V}; I_{B} = 0 \text{ A}$	-		-	1	μΑ
		$V_{CE} = 30 \text{ V}; I_{B} = 0 \text{ A};$ $T_{j} = 150 ^{\circ}\text{C}$	-		-	5	μΑ
I <sub>EBO</sub>	emitter-base cut-off current	$V_{EB} = 5 \text{ V}; I_{C} = 0 \text{ A}$	-		-	90	μΑ
h <sub>FE</sub>	DC current gain	$V_{CE} = 5 \text{ V}; I_{C} = 5 \text{ mA}$	8	0	-	-	
V <sub>CEsat</sub>	collector-emitter saturation voltage	$I_C = 10 \text{ mA}; I_B = 0.5 \text{ mA}$	-		-	150	mV
$V_{I(off)}$	off-state input voltage	$V_{CE} = 5 \text{ V}; I_{C} = 100 \mu\text{A}$	-		1.2	8.0	V
$V_{I(on)}$	on-state input voltage	$V_{CE} = 0.3 \text{ V}; I_{C} = 2 \text{ mA}$	3		1.6	-	V
R1	bias resistor 1 (input)		3	3	47	61	kΩ
R2/R1	bias resistor ratio		0	.8	1	1.2	
C <sub>c</sub>	collector capacitance	$V_{CB} = 10 \text{ V}; I_E = i_e = 0 \text{ A};$ f = 1 MHz	-		-	2.5	pF
f <sub>T</sub>	transition frequency	$V_{CE} = 5 \text{ V; } I_{C} = 10 \text{ mA;}$ f = 100 MHz	[1] _		230	-	MHz

<sup>[1]</sup> Characteristics of built-in transistor



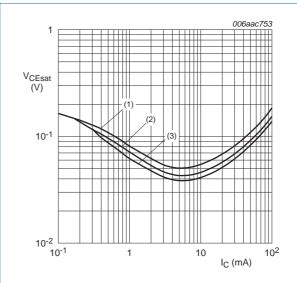
$$V_{CE} = 5 V$$

(1) 
$$T_{amb} = 100 \, ^{\circ}C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = -40 \, ^{\circ}C$$

Fig 6. DC current gain as a function of collector current; typical values



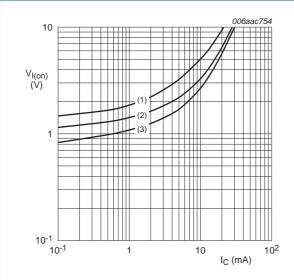
$$I_{\rm C}/I_{\rm B} = 20$$

(1) 
$$T_{amb} = 100 \, ^{\circ}C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = -40 \, ^{\circ}C$$

Fig 7. Collector-emitter saturation voltage as a function of collector current; typical values



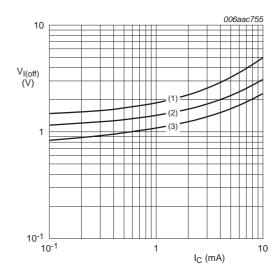
$$V_{CE} = 0.3 \text{ V}$$

(1) 
$$T_{amb} = -40 \, ^{\circ}C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = 100 \, ^{\circ}C$$

Fig 8. On-state input voltage as a function of collector current; typical values



$$V_{CE} = 5 V$$

(1) 
$$T_{amb} = -40 \, ^{\circ}C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = 100 \, ^{\circ}C$$

Fig 9. Off-state input voltage as a function of collector current; typical values

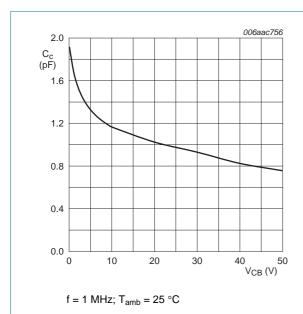


Fig 10. Collector capacitance as a function of collector-base voltage; typical values

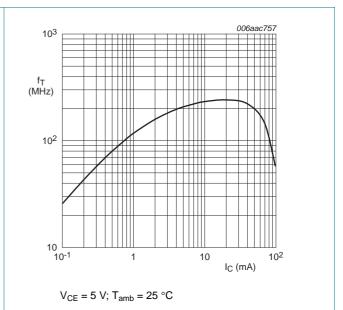


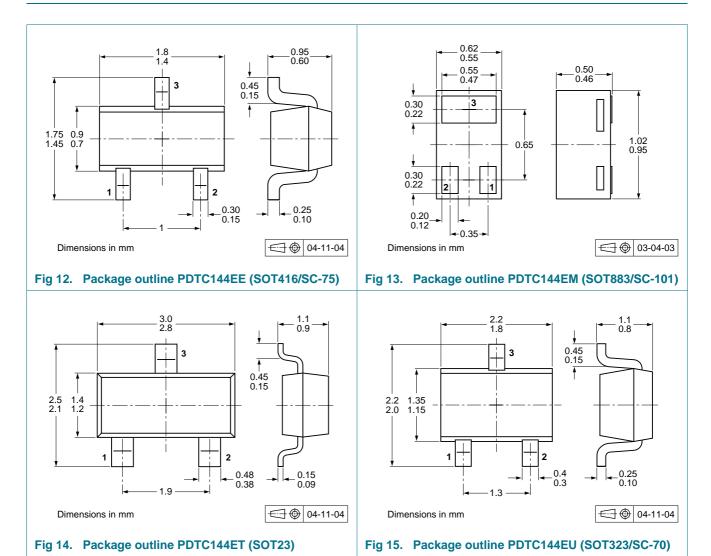
Fig 11. Transition frequency as a function of collector current; typical values of built-in transistor

### 8. Test information

### 8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

## 9. Package outline



## 10. Packing information

#### Table 9. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description	Packing	quantity		
			3000	5000	10000	
PDTC144EE	SOT416	4 mm pitch, 8 mm tape and reel	-115	-	-135	
PDTC144EM	SOT883	2 mm pitch, 8 mm tape and reel	-	-	-315	
PDTC144ET	SOT23	4 mm pitch, 8 mm tape and reel	-215	-	-235	
PDTC144EU	SOT323	4 mm pitch, 8 mm tape and reel	-115	-	-135	

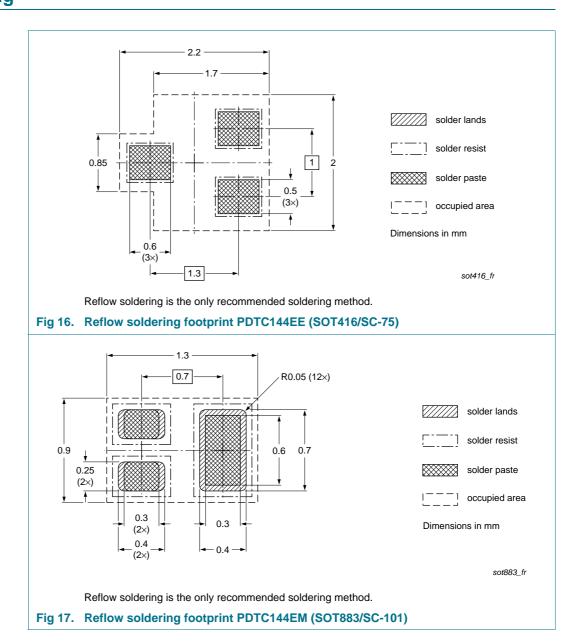
[1] For further information and the availability of packing methods, see Section 14.

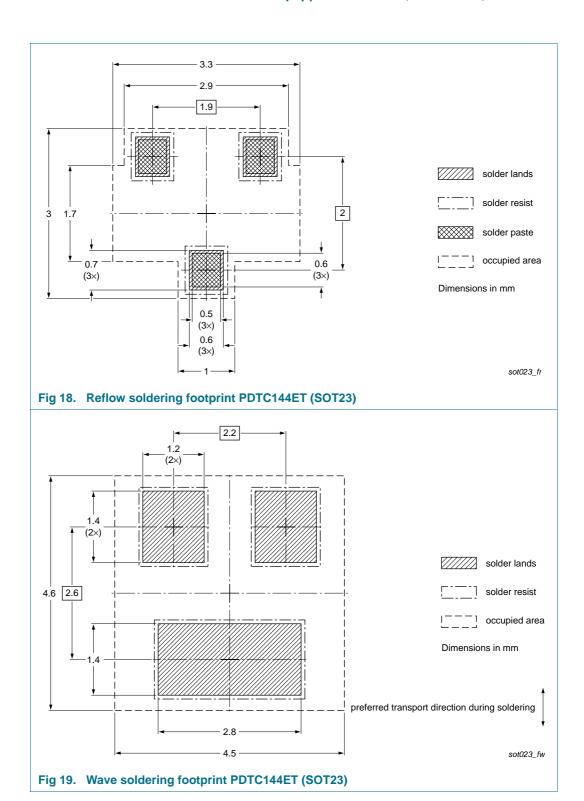
PDTC144E\_SER

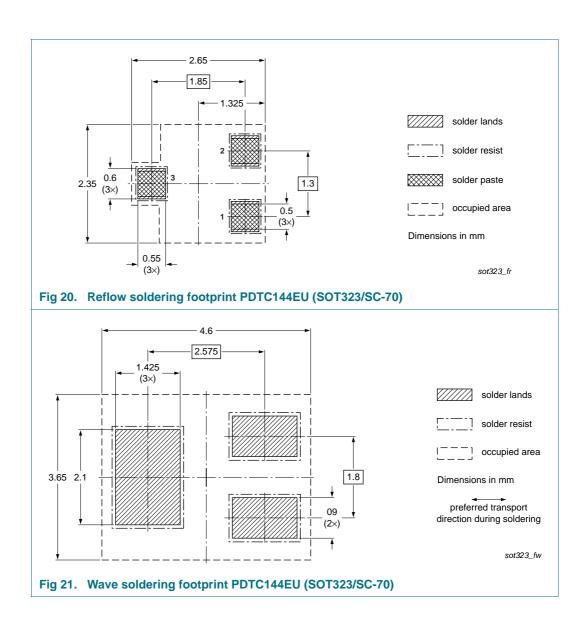
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## 11. Soldering







## 12. Revision history

#### Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes	
PDTC144E_SER v.9	20111115	Product data sheet	-	PDTC144E_SERIES v.8	
Modifications:		f this document has been red NXP Semiconductors.	esigned to comply wi	th the new identity	
	<ul> <li>Legal texts h</li> </ul>	ave been adapted to the new	company name whe	re appropriate.	
	<ul> <li>Type number</li> </ul>	s PDTC144EEF, PDTC144EI	K and PDTC144ES re	emoved.	
	<ul> <li>Section 1 "Pr</li> </ul>	oduct profile": updated			
	<ul> <li>Section 3 "Or</li> </ul>	rdering information": updated			
	<ul> <li>Section 4 "M</li> </ul>	arking": updated			
	<ul> <li>Figure 1 to 1</li> </ul>	<u>1</u> : added			
	Section 6 "Thermal characteristics": updated				
	<ul> <li>Table 8 "Cha</li> </ul>	racteristics": V <sub>i(on)</sub> redefined to	o V <sub>I(on)</sub> on-state input	voltage, $V_{i(off)}$ redefined	
	to V <sub>I(off)</sub> off-st	ate input voltage, I <sub>CEO</sub> update	ed, f <sub>T</sub> added		
	<ul> <li>Section 8 "Te</li> </ul>	est information": added			
	<ul> <li>Section 9 "Pa</li> </ul>	ackage outline": superseded b	y minimized package	e outline drawings	
	<ul> <li>Section 10 "F</li> </ul>	Packing information": added			
	<ul><li>Section 11 "S</li></ul>	Soldering": added			
	<ul> <li>Section 13 "L</li> </ul>	egal information": updated			
PDTC144E_SERIES v.8	20040817	Product data sheet	-	PDTC144E_SERIES v.7	
PDTC144E_SERIES v.7	20040323	Product specification	-	PDTC144E_SERIES v.6	
PDTC144E_SERIES v.6	20030414	Product specification	-	-	

## 13. Legal information

#### 13.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <a href="http://www.nxp.com">http://www.nxp.com</a>.

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# **PDTC144E** series

NPN resistor-equipped transistors; R1 = 47 k $\Omega$ , R2 = 47 k $\Omega$ 

**Quick reference data** — The Quick reference data is an extract of the product data given in the Limiting values and Characteristics sections of this document, and as such is not complete, exhaustive or legally binding.

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# **PDTC144E series**

NPN resistor-equipped transistors; R1 = 47 k $\Omega$ , R2 = 47 k $\Omega$ 

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